

B1AW-F THRU B1MW-F

1 Amperes Surface Mount Super Fast Rectifiers
VOLTAGE : 50 TO 1000Volts

Features	Outline
<ul style="list-style-type: none"> • Low profile surface mounted application in order to optimize board space. • High current capability, low forward voltage drop. • High surge capability. • Superfast recovery time for switching mode application. • Glass passivated chip junction. • Suffix "G" indicates Halogen free parts, ex. B1AWG-F. • Lead-free parts meet environmental standards of MIL-STD-19500 /228 	<p>SOD-123F</p> <p>Dimensions in inches and (millimeters)</p>
Mechanical data	
<ul style="list-style-type: none"> • Epoxy:UL94-V0 rated flame retardant • Case : Molded plastic, SOD-123F • Terminals : Solder plated, solderable per MIL-STD-750, Method 2026 • Polarity : Indicated by cathode band • Weight : Approximated 0.018 gram 	

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbol	B1AW-F	B1BW-F	B1DW-F	B1GW-F	B1JW-F	B1KW-F	B1MW-F	UNIT
Making code		1A	1B	1D, S4	1G	1J	1K	1M	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	
Maximum Forward Voltage	V_F	0.95		1.25		1.70			V
Operating Temperature	T_J	-50 ~ +150							°C

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current		I_O			1.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC methode)	I_{FSM}			30	A
Reverse current	$V_R = V_{RRM} T_A = 25^\circ C$	I_R			1.0	uA
	$V_R = V_{RRM} T_A = 125^\circ C$				300	
Maximum reverse recovery time	$I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A$	T_{rr}			35	nS
Typical junction capacitance	f=1MHz and applied 4V DC reverse voltage	C_j		10		pF

B1AW-F THRU B1MW-F

1 Amperes Surface Mount Super Fast Rectifiers
VOLTAGE : 50 TO 1000Volts

Rating and characteristic curves

FIG.1-TYPICAL FORWARD CHARACTERISTICS

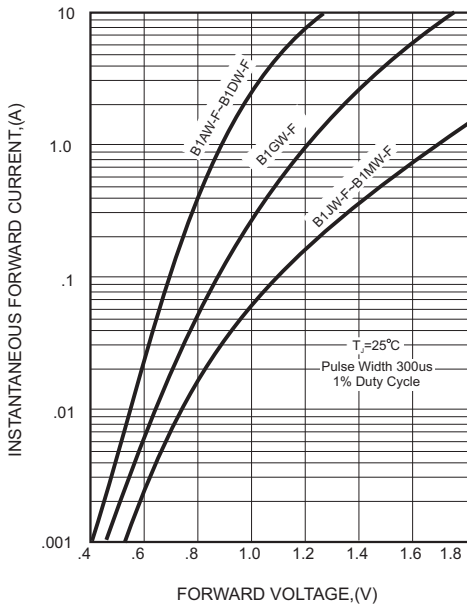


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

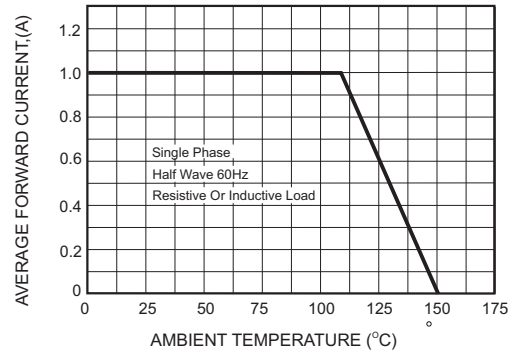
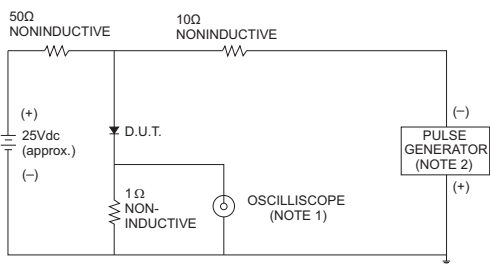


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

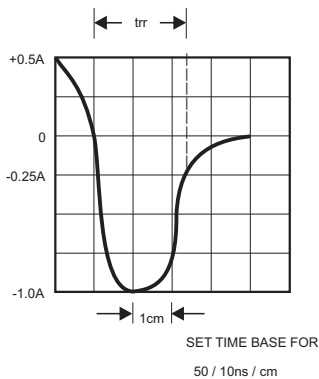


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

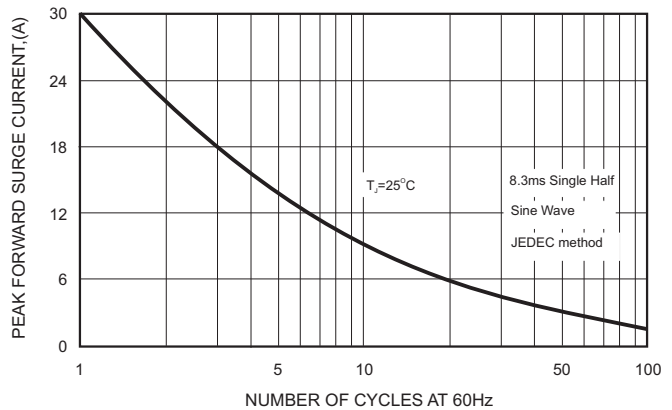


FIG.5-TYPICAL JUNCTION CAPACITANCE

